

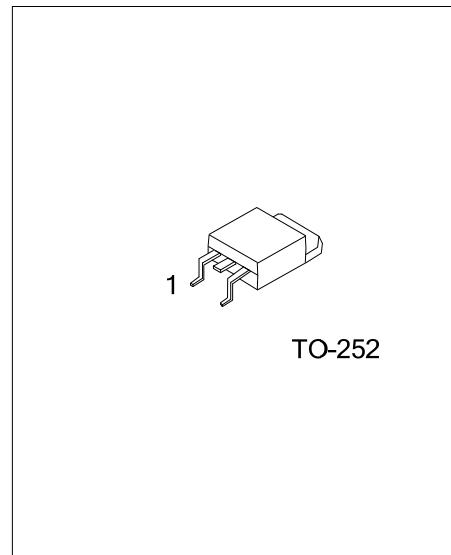
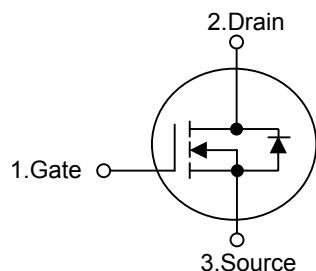
UTN3055**Power MOSFET**

**12A, 25V N-CHANNEL
ENHANCEMENT MODE**

■ DESCRIPTION

The UTC **UTN3055** is N-channel logic level enhancement mode field effect transistor.

■ SYMBOL



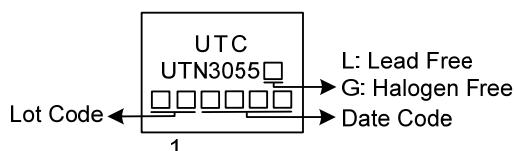
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTN3055L-TN3-R	UTN3055G-TN3-R	TO-252	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

UTN3055G-TN3-R	(1)Packing Type (2)Package Type (3)Green Package	(1) R: Tape Reel (2) TN3: TO-252 (3) G: Halogen Free and Lead Free, L: Lead Free
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■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_c=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V_{DSS}	25	V
Gate-Source Voltage	V_{GSS}	± 20	V
Continuous Drain Current	I_D	12	A
Pulsed Drain Current (Note 1)	I_{DM}	45	A
Repetitive Avalanche Energy ($L=0.05\text{mH}$, Duty Cycle $\leq 1\%$)	E_{AR}	3	mJ
Power Dissipation	P_D	43	W
Junction Temperature	T_J	+150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction-to-Ambient	θ_{JA}	60	$^\circ\text{C}/\text{W}$
Junction-to-Case	θ_{JC}	2.6	$^\circ\text{C}/\text{W}$

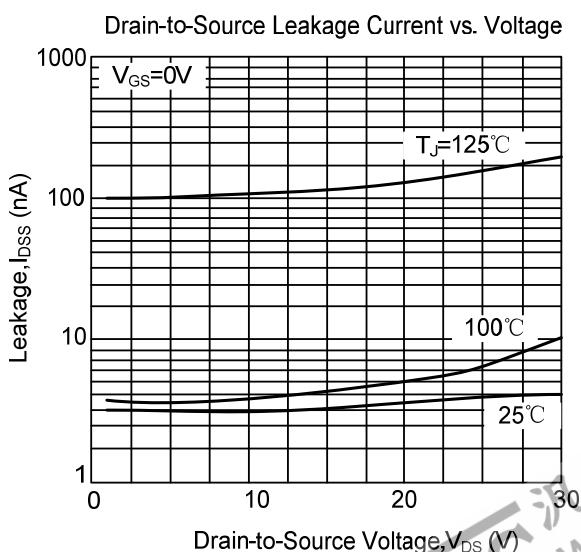
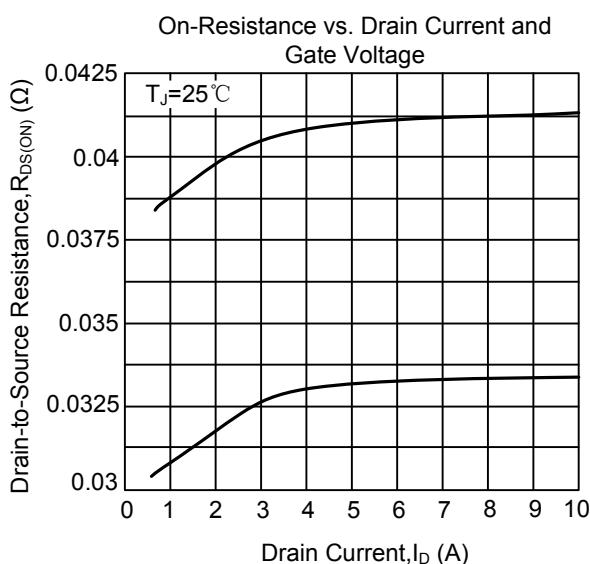
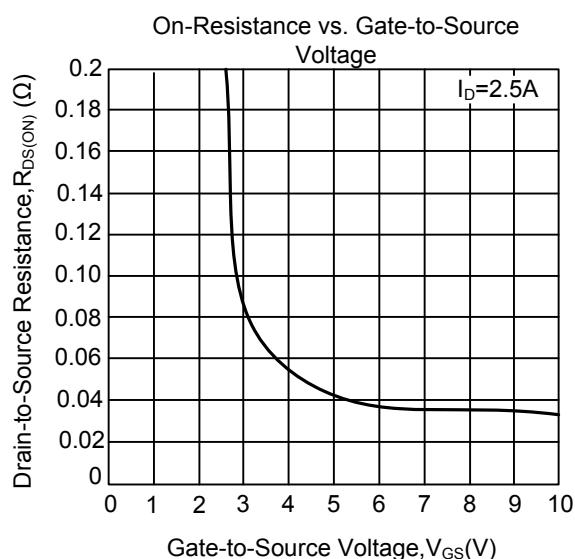
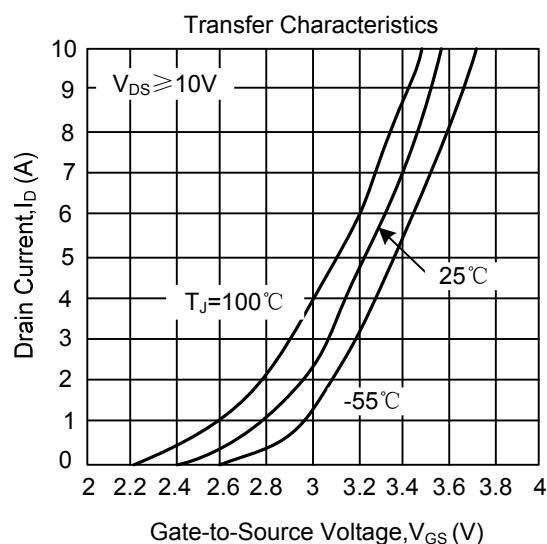
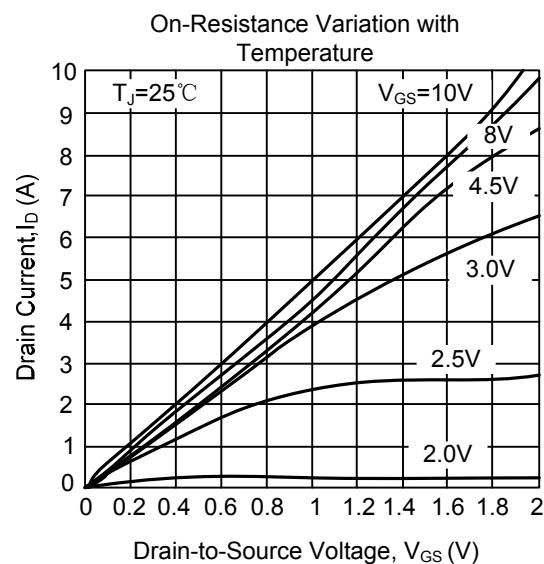
■ ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0\text{V}$, $I_D=250\mu\text{A}$	25			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=20\text{V}$, $V_{GS}=0\text{V}$			25	μA
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0\text{V}$, $V_{GS}=\pm 20\text{V}$			± 250	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	0.8	1.2	2.5	V
On-State Drain Current (Note 2)	$I_{D(\text{ON})}$	$V_{DS}=10\text{V}$, $V_{GS}=10\text{V}$	12			A
Drain-Source On-State Resistance (Note 2)	$R_{DS(\text{ON})}$	$V_{GS}=10\text{V}$, $I_D=12\text{A}$		50	90	$\text{m}\Omega$
		$V_{GS}=5\text{V}$, $I_D=12\text{A}$		70	120	$\text{m}\Omega$
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{ISS}	$V_{GS}=0\text{V}$, $V_{DS}=15\text{V}$, $f=1.0\text{MHz}$		450		pF
Output Capacitance	C_{OSS}			200		pF
Reverse Transfer Capacitance	C_{RSS}			60		pF
SWITCHING CHARACTERISTICS (Note 2)						
Total Gate Charge	Q_G	$V_{DS}=15\text{V}$, $V_{GS}=10\text{V}$, $I_D=6\text{A}$		15		nC
Gate-Source Charge	Q_{GS}			2.0		nC
Gate-Drain Charge	Q_{GD}			7.0		nC
Turn-ON Delay Time	$t_{D(\text{ON})}$			6.0		ns
Turn-ON Rise Time	t_R			6.0		ns
Turn-OFF Delay Time	$t_{D(\text{OFF})}$			20		ns
Turn-OFF Fall Time	t_F			5.0		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Maximum Continuous Drain-Source Diode Forward Current	I_S			12		A
Maximum Pulsed Drain-Source Diode Forward Current (Note 1)	I_{SM}			45		A
Drain-Source Diode Forward Voltage (Note 2)	V_{SD}	$I_F=I_S$, $V_{GS}=0\text{V}$		1.5		V

Notes: 1. Pulse width limited by $T_{J(\text{MAX})}$

2. Pulse width $\leq 300\text{us}$, duty cycle $\leq 2\%$.

■ TYPICAL CHARACTERISTICS



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